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D. Martin  
8-17-02  
H. H. H.

500.40010X00

**IN THE UNITED STATES PATENT AND TRADEMARK OFFICE**

Applicant(s): K. OHNISHI et al  
Serial No.: 09/829,969  
Filed: April 11, 2001  
For: STACKED GATE ELECTRODE FOR A MOS TRANSISTOR  
OF A SEMICONDUCTOR DEVICE (*As Amended*)  
Group: 2818  
Examiner: MAI H.C. TRAN

**AMENDMENT**

Assistant Commissioner of Patents  
Washington, D. C. 20231

Sept. 3, 2002

Sir:

In response to the Office Action dated April 1, 20092, the period of response for which extension of time is requested in the attached Petition for Extension of Time, the following amendments and remarks are respectfully submitted in connection with the above-identified application.

09/04/2002 BSAYAS11 00000098 09829969

01 FC:102  
02 FC:103

84.00 OP  
108.00 OP

**IN THE TITLE:**

Please amend the title to read as follows:

**STACKED GATE ELECTRODE FOR A MOS TRANSISTOR OF A SEMICONDUCTOR DEVICE**

**IN THE SPECIFICATION:**

Please replace the originally submitted Specification with the Substitute Specification enclosed herewith as Attachment A.

RECEIVED  
SEP - 6 2002  
TECHNOLOGY CENTER 2800

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